

T835H, T850H

High temperature 8 A Snubberless™ Triacs

Features

- Medium current Triac
- 150 °C max. T_i turn-off commutation
- Low thermal resistance with clip bonding
- Very high 3 quadrant commutation capability
- Packages are RoHS (2002/95/EC) compliant
- UL certified (ref. file E81734)

Applications

Especially designed to operate in high power density or universal motor applications such as vacuum cleaner and washing machine drum motor, these 8 A Triacs provide a very high switching capability up to junction temperatures of 150 °C.

The heatsink can be reduced, compared to traditional Triac, according to the high performance at given junction temperatures.

Description

Available in through-hole or surface mount packages, the T835H and T850H Triacs series are suitable for general purpose mains power ac switching.

By using an internal ceramic pad, the T8xxH-6I provides voltage insulation (rated at 2500 V rms).

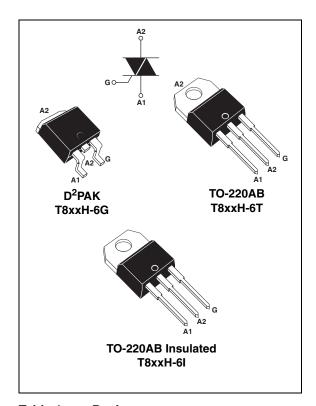


Table 1. Device summary

Symbol	Value	Unit
I _{T(RMS)}	8	Α
V_{DRM}/V_{RRM}	600	V
I _{GT}	35 or 50	mA

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1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Parameter			Value	Unit
	On state rms surrent (full sine ways)	D ² PAK, TO-220AB $T_c = 136 ^{\circ}\text{C}$		- 8	Α
I _{T(RMS)}	On-state rms current (full sine wave)	TO-220AB Ins	T _c = 123 °C	0	A
L	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	80	Α
I _{TSM}	current (full cycle, T _j initial = 25 °C)	F = 60 Hz	t = 16.7 ms	84	A
l ² t	I ² t Value for fusing	t _p = 10 ms		42	A ² s
dI/dt	Critical rate of rise of on-state current I_G = 2 x I_{GT} , $t_r \le 100$ ns	F = 120 Hz	T _j = 150 °C	50	A/µs
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voltage	t _p = 10 ms	T _j = 25 °C	V _{DRM} /V _{RRM} + 100	V
I _{GM}	Peak gate current $t_p = 20 \mu s$ $T_j = 150 ^{\circ} C$		4	Α	
P _{G(AV)}	Average gate power dissipation $T_j = 150 ^{\circ}\text{C}$			1	W
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	°C

Table 3. Electrical characteristics (T_j = 25 °C, unless otherwise specified)

Symbol	Test conditions	Quadrant		Value		Unit
Symbol	rest conditions	Quadrant		T835H	T850H	Oilit
I _{GT} ⁽¹⁾	V _D = 12 V, R _I = 33 Ω	1 - 11 - 111	MAX.	35	50	mA
V _{GT}	VD = 12 v, 11L = 33 22	1 - 11 - 111	MAX.	1	.0	V
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ I - II - III		MIN.	0.15		V
I _H ⁽²⁾	I _T = 500 mA	•	MAX.	35	75	mA
1	1 -121	1 - 111	MAX. 50	60	mA	
IL	$I_{G} = 1.2 I_{GT}$	II	IVIAA.	80	110	ША
dV/dt (2)	$V_D = 67\% V_{DRM,}$ gate open, $T_j = 150 ^{\circ}\text{C}$		MIN.	1000	1500	V/µs
(dl/dt)c (2)	Without snubber, T _j = 150 °C		MIN.	11	14	A/ms

^{1.} minimum $I_{\mbox{\footnotesize{GT}}}$ is guaranted at 20% of $I_{\mbox{\footnotesize{GT}}}$ max.

^{2.} for both polarities of A2 referenced to A1.

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Table 4. Static characteristics

Symbol	Test conditions			Value	Unit
V _T ⁽¹⁾	$I_{TM} = 11 \text{ A, } t_p = 380 \mu\text{s}$	T _j = 25 °C	MAX.	1.5	V
V _{t0} (1)	Threshold voltage	T _j = 150 °C	MAX.	0.80	V
R _d ⁽¹⁾	Dynamic resistance	T _j = 150 °C	MAX.	25	mΩ
	W - W	T _j = 25 °C	MAX.	5	μΑ
I _{DRM}	$V_{DRM} = V_{RRM}$	T _j = 150 °C	MAX.	3.1	
I _{RRM} ⁽²⁾	V _D /V _R = 400 V (at peak mains voltage)	T _j = 150 °C	MAX.	2.5	mA
	V _D /V _R = 200 V (at peak mains voltage)	T _j = 150 °C	MAX.	2.0	

^{1.} for both polarities of A2 referenced to A1

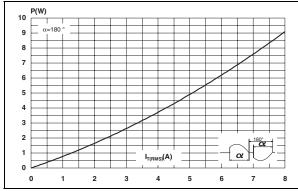
Table 5. Thermal resistance

Symbol	Parameter			Value	Unit
D	R _{th(j-c)} Junction to case (AC)		D ² PAK / TO-220AB	1.85	
¹¹th(j-c)			TO-220AB Ins	3.7	°C/W
Rep/(a) Junction to ambient		$S = 1 \text{ cm}^2$	D ² PAK	45	C/VV
R _{th(j-a)}	Junction to ambient		TO-220AB / TO-220AB Ins	60	

^{2.} $t_p = 380 \ \mu s$

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Figure 1. Maximum power dissipation versus Figure 2. On-state rms current versus case on-state rms current (full cycle) temperature (full cycle)



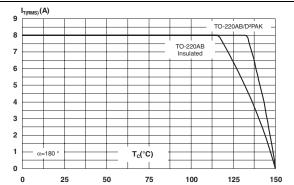
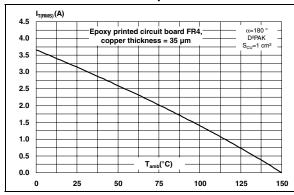


Figure 3. On-state rms current versus ambient temperature

Figure 4. Variation of thermal impedance versus pulse duration



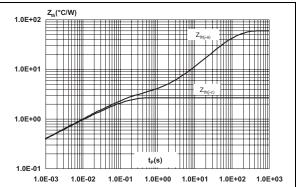
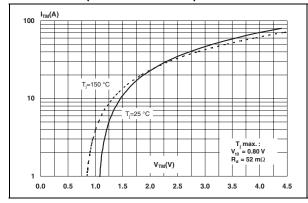
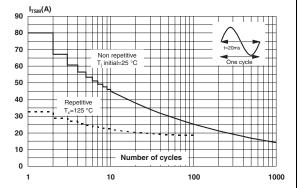


Figure 5. On-state characteristics (maximum values)

Figure 6. Surge peak on-state current versus number of cycles



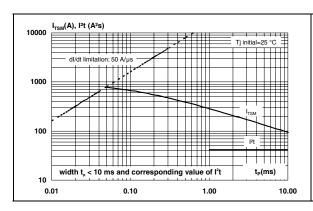


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Figure 7. Non-repetitive surge peak on-state Figure 8. current for a sinusoidal pulse with

gure 8. Relative variation of I_{GT},I_H, I_L vs junction temperature (typical values)



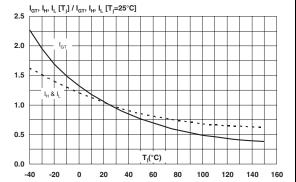
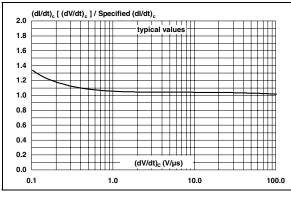


Figure 9. Relative variation of critical rate of decrease of main current (dl/dt)c versus reapplied (dV/dt)c

Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature



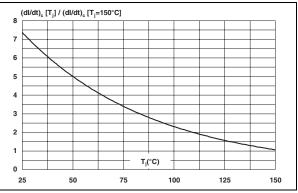
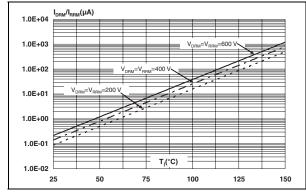
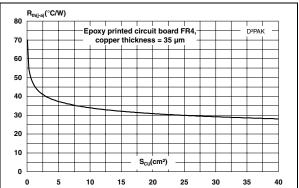


Figure 11. Leakage current versus junction temperature for different values of blocking voltage (typical values)

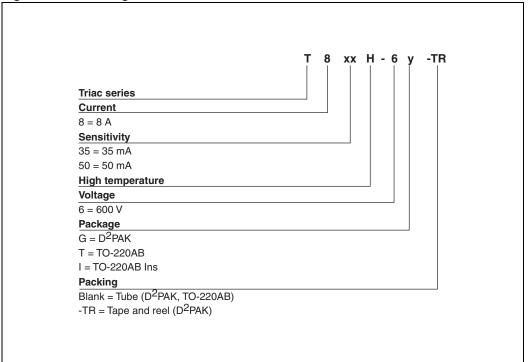
Figure 12. Variation of thermal resistance junction to ambient versus copper surface under tab





2 Ordering information scheme

Figure 13. Ordering information scheme



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3 **Package information**

- Epoxy meets UL94, V0
- Recommended torque 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

D²PAK dimensions Table 6.

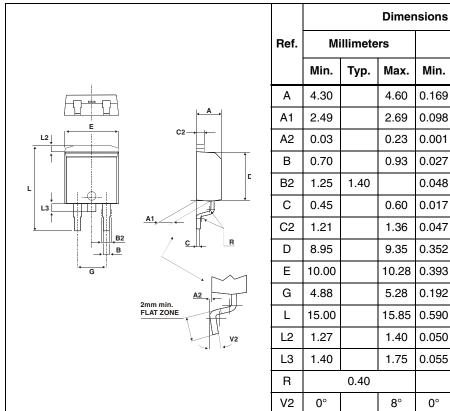
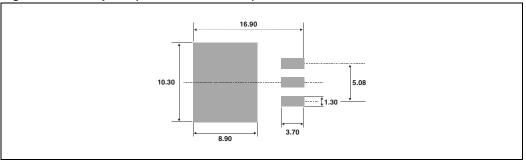


Figure 14. Footprint (dimensions in mm)





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Inches

Typ.

0.055

0.016

Max.

0.181

0.106

0.009

0.037

0.024

0.054

0.368

0.405

0.208

0.624

0.055

0.069

8°

Min.

0.169

0.098

0.001

0.027

0.048

0.017

0.047

0.352

0.393

0.192

0.590

0.050

0.055

0°

Dimensions Ref. Millimeters Inches Min. Тур. Max. Min. Тур. Max. 0.598 0.625 Α 15.20 15.90 a1 3.75 0.147 В a2 13.00 14.00 0.511 0.551 Ø١ В 10.00 10.40 0.393 0.409 ÎL. 0.88 0.024 0.034 b1 0.61 1.23 1.32 0.048 0.051 b2 14 С 0.181 4.40 4.60 0.173 13 0.027 с1 0.49 0.70 0.019 c2 c2 2.40 2.72 0.094 0.107 a2 2.40 2.70 0.094 0.106 е F 6.60 0.244 0.259 6.20 с1 ØΙ 3.75 3.85 0.147 0.151 14 15.80 16.40 16.80 0.622 0.646 0.661 L 0.116 2.65 2.95 0.104 12 1.14 1.70 0.044 0.066 l3 1.14 1.70 0.044 0.066 М 2.60 0.102

Table 7. TO-220AB and TO-220AB Ins dimensions



4 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T8xxH-6G	T8xxH 6G	D ² PAK	1.5 g	50	Tube
T8xxH-6G-TR	T8xxH 6G	D ² PAK	1.5 g	1000	Tape and reel
T8xxH-6T	T8xxH 6T	TO-220AB	2.3 g	50	Tube
T8xxH-6I	T8xxH 6I	TO-220AB Ins	2.3 g	50	Tube

5 Revision history

Table 9. Document revision history

Date	Revision	Changes
17-Apr-2007	1	First issue.
19-Sep-2011	2	Udated: Features, Description, Figure 2, Table 2 and 4.

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